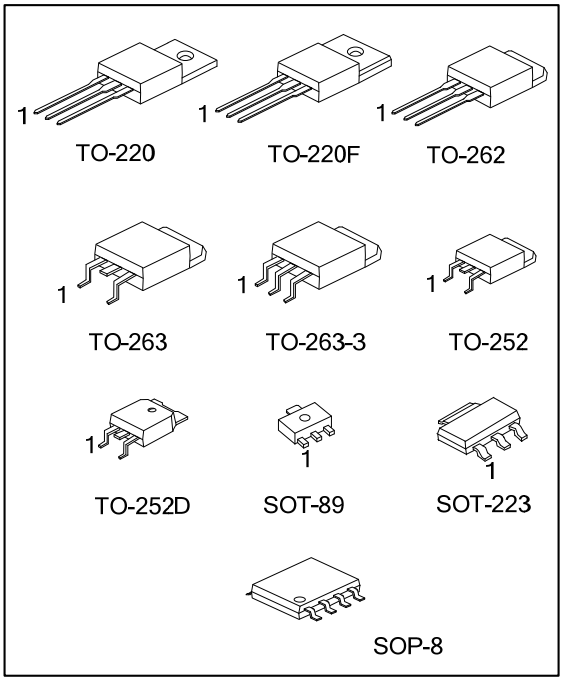
LD1117/A

LINEAR INTEGRATED CIRCUIT

LOW DROP FIXED AND ADJUSTABLE POSITIVE VOLTAGE REGULATORS



■ DESCRIPTION

The UTC **LD1117/A** is a low dropout, 3-terminal positive voltage regulator designed to provide output current up to 800mA/1A, There are adjustable version (V_{REF}=1.25V) and various fixed versions.

■ FEATURES

* Low dropout voltage
* Suitable for SCSI-2 active termination if V_{OUT} set to 2.85V
* Output current up to 0.8A for 1117 and 1.0A for 1117A
* Built-in current limit and over temperature protection
* Low current consumption
* Support MLCC

■ ORDERING INFORMATION

Ordering Number		Package	② Pin Assignment	③ Packing
Lead Free	Halogen Free			
LD1117①L-xx-AA3-②-③	LD1117①G-xx-AA3-②-③	SOT-223		R: Tape Reel T: Tube
LD1117①L-xx-AB3-②-③	LD1117①G-xx-AB3-②-③	SOT-89		
LD1117①L-xx-TA3-②-③	LD1117①G-xx-TA3-②-③	TO-220		
LD1117①L-xx-TF3-②-③	LD1117①G-xx-TF3-②-③	TO-220F		
LD1117①L-xx-TN3-②-③	LD1117①G-xx-TN3-②-③	TO-252		
LD1117①L-xx-TND-②-③	LD1117①G-xx-TND-②-③	TO-252D		
LD1117①L-xx-T2Q-②-③	LD1117①G-xx-T2Q-②-③	TO-262		
LD1117①L-xx-TQ2-②-③	LD1117①G-xx-TQ2-②-③	TO-263		
LD1117①L-xx-TQ3-②-③	LD1117①G-xx-TQ3-②-③	TO-263-3		
LD1117①L-xx-S08-②-③	LD1117①G-xx-S08-②-③	SOP-8	GOOIxOOx	

Pin Code	1	2	3
A	G	O	I
B	O	G	I
C	G	I	O
D	I	G	O

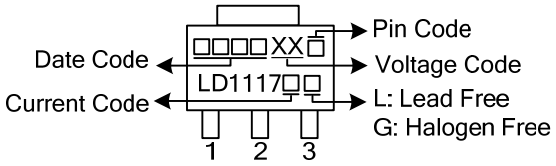
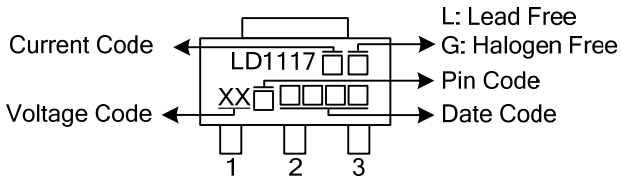
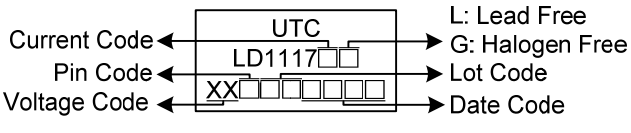
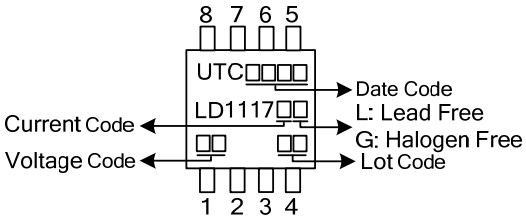
Notes: 1. ① : Current code: Blank: 800mA A: 1A
2. Pin Assignment: I: V_{IN} O: V_{OUT} G: GND/ADJ
3. xx: Output Voltage, Refer to Marking Information.

LD1117①G-xx-AA3-②-③

(1)Packing Type
(2)Pin Assignment
(3)Package Type
(4)Output Voltage Code
(5)Green Package
(6)Current Code

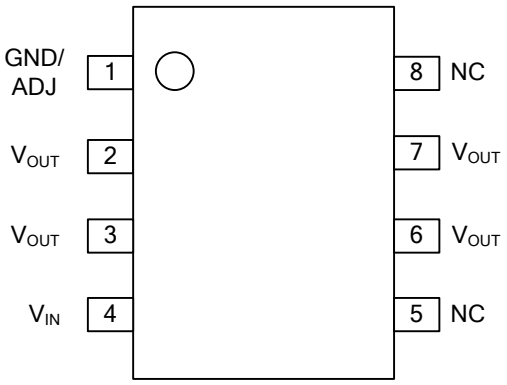
(1) R: Tape Reel, T: Tube
(2) refer to Pin Assignment
(3) AA3: SOT-223, AB3: SOT-89, TA3:TO-220, TF3: TO-220F, TN3: TO-252, TND: TO-252D T2Q: TO-262, TQ2: TO-263, TQ3: TO-263-3, S08: SOP-8
(4) xx: refer to Marking Information
(5) G: Halogen Free and Lead Free, L: Lead Free
(6) Blank: 800mA, A: 1A

■ MARKING INFORMATION

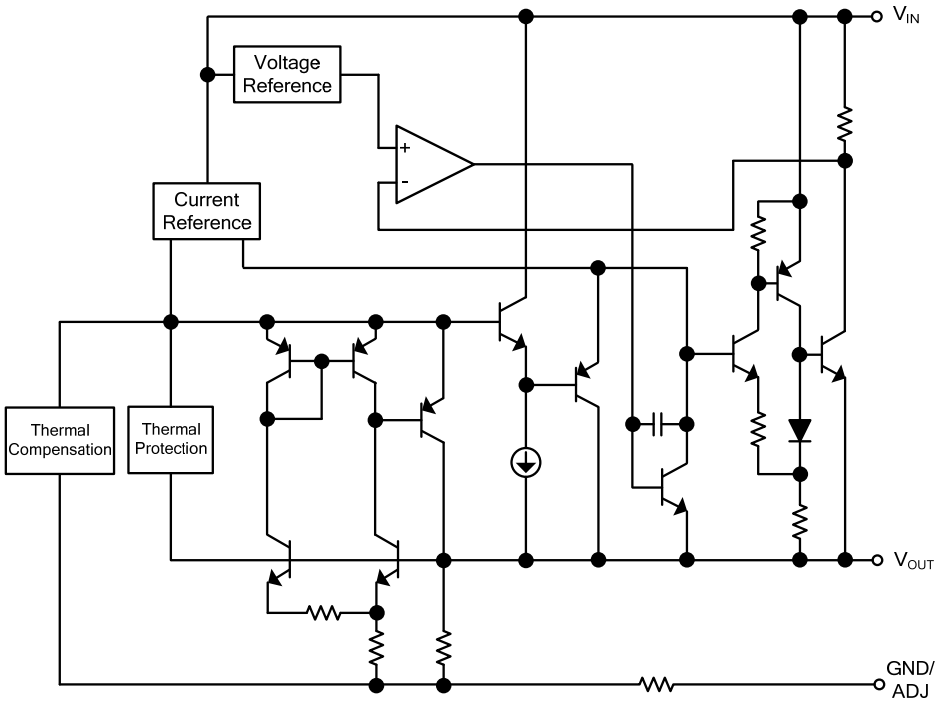
PACKAGE	VOLTAGE CODE	MARKING
SOT-89	12 :1.2V 15 :1.5V 18 :1.8V 25 :2.5V 2J :2.85V 30 :3.0V 33 :3.3V 36 :3.6V 50 :5.0V AD :ADJ	
SOT-223		
TO-220 TO-220F TO-252 TO-252D TO-262 TO-263 TO-263-3		
SOP-8		

Note: Current code: Blank: 0.8A A: 1A

■ PIN CONFIGURATION of SOP-8



■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS (T_A=25°C)

PARAMETER	SYMBOL	RATINGS	UNIT
DC Input Voltage	V_{IN}	18	V
Power Dissipation	P_D	Internally limited	
Junction Temperature	T_J	+150	°C
Operating Temperature (Note 2)	T_{OPR}	-20 ~ +125	°C
Storage temperature	T_{STG}	-65 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
2. This condition is only determined from design. It can't be 100% tested in mass production.

■ RECOMMENDED OPERATING RATINGS

PARAMETER	SYMBOL	RATINGS	UNIT
Input Voltage	V_{IN}	15	V
Operating Junction Temperature	T_J	-20 ~ +125	°C

■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	SOT-223	θ_{JA}	165	°C/W
	SOT-89		180	°C/W
	SOP-8		150	°C/W
	TO-252/TO-252D		112	°C/W
	TO-220		54	°C/W
	TO-262/TO-263		64	°C/W
Junction to Case	SOT-223	θ_{JC}	15	°C/W
	SOT-89		50	°C/W
	SOP-8		20	°C/W
	TO-252/TO-252D		12	°C/W
	TO-220/TO-262 TO-263		4	°C/W

■ ELECTRICAL CHARACTERISTICS

(T_A=25°C, refer to the test circuits, T_J=0 ~ 125°C, C_O=10μF unless otherwise specified)

For LD1117/A-1.2

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Output Voltage	V_{OUT}	V_{IN}=3.2V, I_{OUT}=10mA, T_J=25°C		1.176	1.200	1.224	V
Output Voltage	V_{OUT}	V_{IN}=2.7 to 8V LD1117 : I_{OUT}=10~800mA LD1117A : I_{OUT}=10~1000mA		1.176	1.200	1.224	V
Line Regulation	ΔV_{OUT}	V_{IN}=2.7 to 8V, I_{OUT}=10mA			1	6	mV
Load Regulation	ΔV_{OUT}	V_{IN}=2.7V LD1117 : I_{OUT}=10~800mA LD1117A : I_{OUT}=10~1000mA			1	10	mV
Temperature stability	ΔV_{OUT}				0.5		%
Long Term Stability	ΔV_{OUT}	1000 hrs, T_J=125°C			0.3		%
Operating Input Voltage	V_{IN}	I_{OUT}=100mA				15	V
Quiescent Current	I_Q	V_{IN}≤10V			5	10	mA
Current Limit	I_{LIMIT}	V_{IN}=6.2V, T_J=25°C	LD1117	800			mA
			LD1117A	1000			
Minimum Load Current	$I_{O(MIN)}$	V_{IN}=15V			2	5	mA
Output Noise Voltage	e_N	B=10Hz to 10KHz, T_J=25°C			100		μV
Supply Voltage Rejection	SVR	I_{OUT}=40mA, f=120Hz, T_J=25°C, V_{IN}=4.2V, V_{RIPPLE} =1V_{PP}		60	75		dB
Dropout Voltage	V_D	I_{OUT}=100mA			1.00	1.10	V
		I_{OUT}=500mA			1.15	1.25	
		I_{OUT}=800mA			1.20	1.30	
		I_{OUT}=1A			1.20	1.30	
Thermal Regulation		T_A=25°C, 30ms Pulse			0.01	0.10	%/W

For LD1117/A-1.5

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Output Voltage	V_{OUT}	V_{IN}=3.5V, I_{OUT}=10mA, T_J=25°C		1.470	1.500	1.530	V
Output Voltage	V_{OUT}	V_{IN}=3 to 8V LD1117 : I_{OUT}=0~800mA LD1117A : I_{OUT}=0~1000mA		1.470	1.500	1.530	V
Line Regulation	ΔV_{OUT}	V_{IN}=3 to 8V, I_{OUT}=0mA			1	6	mV
Load Regulation	ΔV_{OUT}	V_{IN}=3V LD1117 : I_{OUT}=0~800mA LD1117A : I_{OUT}=0~1000mA			1	10	mV
Temperature stability	ΔV_{OUT}				0.5		%
Long Term Stability	ΔV_{OUT}	1000 hrs, T_J=125°C			0.3		%
Operating Input Voltage	V_{IN}	I_{OUT}=100mA				15	V
Quiescent Current	I_Q	V_{IN}≤10V			5	10	mA
Current Limit	I_{LIMIT}	V_{IN}=6.5V, T_J=25°C	LD1117	800			mA
			LD1117A	1000			
Output Noise Voltage	e_N	B=10Hz to 10KHz, T_J=25°C			100		μV
Supply Voltage Rejection	SVR	I_{OUT}=40mA, f=120Hz, T_J=25°C, V_{IN}=4.5V, V_{RIPPLE}=1V_{PP}		60	75		dB
Dropout Voltage	V_D	I_{OUT}=100mA			1.00	1.10	V
		I_{OUT}=500mA			1.15	1.25	
		I_{OUT}=800mA			1.20	1.30	
		I_{OUT}=1A			1.20	1.30	
Thermal Regulation		T_A=25°C, 30ms Pulse			0.01	0.10	%/W

■ ELECTRICAL CHARACTERISTICS(Cont.)

For LD1117/A-1.8

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Output Voltage	V_{OUT}	V_{IN}=3.8V, I_{OUT}=10mA, T_J=25°C		1.764	1.800	1.836	V
Output Voltage	V_{OUT}	V_{IN}=3.3 to 8V LD1117 : I_{OUT}=0~800mA LD1117A : I_{OUT}=0~1000mA		1.764	1.800	1.836	V
Line Regulation	ΔV_{OUT}	V_{IN}=3.3 to 8V, I_{OUT}=0mA			1	6	mV
Load Regulation	ΔV_{OUT}	V_{IN}=3.3V LD1117 : I_{OUT}=0~800mA LD1117A : I_{OUT}=0~1000mA			1	10	mV
Temperature stability	ΔV_{OUT}				0.5		%
Long Term Stability	ΔV_{OUT}	1000 hrs, T_J=125°C			0.3		%
Operating Input Voltage	V_{IN}	I_{OUT}=100mA				15	V
Quiescent Current	I_Q	$V_{IN}\leq$10V			5	10	mA
Current Limit	I_{LIMIT}	V_{IN}=6.8V, T_J=25°C	LD1117	800			mA
			LD1117A	1000			
Output Noise Voltage	e_N	B=10Hz to 10KHz, T_J=25°C			100		μV
Supply Voltage Rejection	SVR	I_{OUT}=40mA, f=120Hz, T_J=25°C, V_{IN}=5.5V, V_{RIPPLE}=1V_{PP}		60	75		dB
Dropout Voltage	V_D	I_{OUT}=100mA			1.00	1.10	V
		I_{OUT}=500mA			1.15	1.25	
		I_{OUT}=800mA			1.20	1.30	
		I_{OUT}=1A			1.20	1.30	
Thermal Regulation		T_A=25°C, 30ms Pulse			0.01	0.10	%/W

For LD1117/A-2.5

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Output Voltage	V_{OUT}	V_{IN}=4.5V, I_{OUT}=10mA, T_J=25°C		2.450	2.500	2.550	V
Output Voltage	V_{OUT}	V_{IN}=3.9 to 10V LD1117 : I_{OUT}=0~800mA LD1117A : I_{OUT}=0~1000mA		2.450	2.500	2.550	V
Line Regulation	ΔV_{OUT}	V_{IN}=3.9 to 10V, I_{OUT}=0mA			1	6	mV
Load Regulation	ΔV_{OUT}	V_{IN}=3.9V LD1117 : I_{OUT}=0~800mA LD1117A : I_{OUT}=0~1000mA			1	10	mV
Temperature stability	ΔV_{OUT}				0.5		%
Long Term Stability	ΔV_{OUT}	1000 hrs, T_J=125°C			0.3		%
Operating Input Voltage	V_{IN}	I_{OUT}=100mA				15	V
Quiescent Current	I_Q	$V_{IN}\leq$10V			5	10	mA
Current Limit	I_{LIMIT}	V_{IN}=7.5V, T_J=25°C	LD1117	800			mA
			LD1117A	1000			
Output Noise Voltage	e_N	B=10Hz to 10KHz, T_J=25°C			100		μV
Supply Voltage Rejection	SVR	I_{OUT}=40mA, f=120Hz, T_J=25°C, V_{IN}=5.5V, V_{RIPPLE} =1V_{PP}		60	75		dB
Dropout Voltage	V_D	I_{OUT}=100mA			1.00	1.10	V
		I_{OUT}=500mA			1.15	1.25	
		I_{OUT}=800mA			1.20	1.30	
		I_{OUT}=1A			1.20	1.30	
Thermal Regulation		T_A=25°C, 30ms Pulse			0.01	0.10	%/W

■ ELECTRICAL CHARACTERISTICS(Cont.)

For LD1117/A-2.85

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Output Voltage	V_{OUT}	V_{IN}=4.85V, I_{OUT}=10mA, T_J=25°C		2.793	2.850	2.907	V
Output Voltage	V_{OUT}	V_{IN}=4.25 to 10V LD1117 : I_{OUT}=0~800mA LD1117A : I_{OUT}=0~1000mA		2.793	2.850	2.907	V
Line Regulation	ΔV_{OUT}	V_{IN}=4.25 to 10V, I_{OUT}=0mA			1	6	mV
Load Regulation	ΔV_{OUT}	V_{IN}=4.25V LD1117 : I_{OUT}=0~800mA LD1117A : I_{OUT}=0~1000mA			1	10	mV
Temperature stability	ΔV_{OUT}				0.5		%
Long Term Stability	ΔV_{OUT}	1000 hrs, T_J=125°C			0.3		%
Operating Input Voltage	V_{IN}	I_{OUT}=100mA				15	V
Quiescent Current	I_Q	V_{IN}≤10V			5	10	mA
Current Limit	I_{LIMIT}	V_{IN}=7.85V, T_J=25°C	LD1117	800			mA
			LD1117A	1000			
Output Noise Voltage	e_N	B=10Hz to 10KHz, T_J=25°C			100		μV
Supply Voltage Rejection	SVR	I_{OUT}=40mA, f=120Hz, T_J=25°C, V_{IN}=5.85V, V_{RIPPLE}=1V_{PP}		60	75		dB
Dropout Voltage	V_D	I_{OUT}=100mA			1.00	1.10	V
		I_{OUT}=500mA			1.15	1.25	
		I_{OUT}=800mA			1.20	1.30	
		I_{OUT}=1A			1.20	1.30	
Thermal Regulation		T_A=25°C, 30ms Pulse			0.01	0.10	%/W

For LD1117/A-3.0

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Output Voltage	V_{OUT}	V_{IN}=5V, I_{OUT}=10mA, T_J=25°C		2.940	3.000	3.060	V
Output Voltage	V_{OUT}	V_{IN}=4.5 to 10V LD1117 : I_{OUT}=0~800mA LD1117A : I_{OUT}=0~1000mA		2.940	3.000	3.060	V
Line Regulation	ΔV_{OUT}	V_{IN}=4.5 to 12V, I_{OUT}=0mA			1	6	mV
Load Regulation	ΔV_{OUT}	V_{IN}=4.5V LD1117 : I_{OUT}=0~800mA LD1117A : I_{OUT}=0~1000mA			1	10	mV
Temperature stability	ΔV_{OUT}				0.5		%
Long Term Stability	ΔV_{OUT}	1000 hrs, T_J=125°C			0.3		%
Operating Input Voltage	V_{IN}	I_{OUT}=100mA				15	V
Quiescent Current	I_Q	V_{IN}≤15V			5	10	mA
Current Limit	I_{LIMIT}	V_{IN}=8V, T_J=25°C	LD1117	800			mA
			LD1117A	1000			
Output Noise Voltage	e_N	B=10Hz to 10KHz, T_J=25°C			100		μV
Supply Voltage Rejection	SVR	I_{OUT}=40mA, f=120Hz, T_J=25°C, V_{IN}=6V, V_{RIPPLE}=1V_{PP}		60	75		dB
Dropout Voltage	V_D	I_{OUT}=100mA			1.00	1.10	V
		I_{OUT}=500mA			1.15	1.25	
		I_{OUT}=800mA			1.20	1.30	
		I_{OUT}=1A			1.20	1.30	
Thermal Regulation		T_A=25°C, 30ms Pulse			0.01	0.10	%/W

■ ELECTRICAL CHARACTERISTICS(Cont.)

For LD1117/A-3.3

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Output Voltage	V_{OUT}	V_{IN}=5.3V, I_{OUT}=10mA, T_J=25°C		3.234	3.300	3.366	V
Output Voltage	V_{OUT}	V_{IN}=4.75 to 10V LD1117 : I_{OUT}=0~800mA LD1117A : I_{OUT}=0~1000mA		3.234	3.300	3.366	V
Line Regulation	ΔV_{OUT}	V_{IN}=4.75 to 15V, I_{OUT}=0mA			1	6	mV
Load Regulation	ΔV_{OUT}	V_{IN}=4.75V LD1117 : I_{OUT}=0~800mA LD1117A : I_{OUT}=0~1000mA			1	10	mV
Temperature stability	ΔV_{OUT}				0.5		%
Long Term Stability	ΔV_{OUT}	1000 hrs, T_J=125°C			0.3		%
Operating Input Voltage	V_{IN}	I_{OUT}=100mA				15	V
Quiescent Current	I_Q	V_{IN}≤15V			5	10	mA
Current Limit	I_{LIMIT}	V_{IN}=8.3V, T_J=25°C	LD1117	800			mA
			LD1117A	1000			
Output Noise Voltage	e_N	B=10Hz to 10KHz, T_J=25°C			100		μV
Supply Voltage Rejection	SVR	I_{OUT}=40mA, f=120Hz, T_J=25°C, V_{IN}=6.3V, V_{RIPPLE}=1V_{PP}		60	75		dB
Dropout Voltage	V_D	I_{OUT}=100mA			1.00	1.10	V
		I_{OUT}=500mA			1.15	1.25	
		I_{OUT}=800mA			1.20	1.30	
		I_{OUT}=1A			1.20	1.30	
Thermal Regulation		T_A=25°C, 30ms Pulse			0.01	0.10	%/W

For LD1117/A-3.6

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Output Voltage	V_{OUT}	V_{IN}=5.6V, I_{OUT}=10mA, T_J=25°C		3.528	3.600	3.672	V
Output Voltage	V_{OUT}	V_{IN}=5 to 10V LD1117 : I_{OUT}=0~800mA LD1117A : I_{OUT}=0~1000mA		3.528	3.600	3.672	V
Line Regulation	ΔV_{OUT}	V_{IN}=5 to 15V, I_{OUT}=0mA			1	6	mV
Load Regulation	ΔV_{OUT}	V_{IN}=5V LD1117 : I_{OUT}=0~800mA LD1117A : I_{OUT}=0~1000mA			1	10	mV
Temperature stability	ΔV_{OUT}				0.5		%
Long Term Stability	ΔV_{OUT}	1000 hrs, T_J=125°C			0.3		%
Operating Input Voltage	V_{IN}	I_{OUT}=100mA				15	V
Quiescent Current	I_Q	V_{IN}≤15V			5	10	mA
Current Limit	I_{LIMIT}	V_{IN}=8.6V, T_J=25°C	LD1117	800			mA
			LD1117A	1000			
Output Noise Voltage	e_N	B=10Hz to 10KHz, T_J=25°C			100		μV
Supply Voltage Rejection	SVR	I_{OUT}=40mA, f=120Hz, T_J=25°C, V_{IN}=6.6V, V_{RIPPLE}=1V_{PP}		60	75		dB
Dropout Voltage	V_D	I_{OUT}=100mA			1.00	1.10	V
		I_{OUT}=500mA			1.15	1.25	
		I_{OUT}=800mA			1.20	1.30	
		I_{OUT}=1A			1.20	1.30	
Thermal Regulation		T_A=25°C, 30ms Pulse			0.01	0.10	%/W

■ ELECTRICAL CHARACTERISTICS(Cont.)

For LD1117/A-5.0

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Output Voltage	V_{OUT}	V_{IN}=7V, I_{OUT}=10mA, T_J=25°C		4.900	5.000	5.100	V
Output Voltage	V_{OUT}	V_{IN}=6.5 to 15V LD1117 : I_{OUT}=0~800mA LD1117A : I_{OUT}=0~1.0A		4.900	5.000	5.100	V
Line Regulation	ΔV_{OUT}	V_{IN}=6.5 to 15V, I_{OUT}=0mA			1	10	mV
Load Regulation	ΔV_{OUT}	V_{IN}=6.5V LD1117 : I_{OUT}=0~800mA LD1117A : I_{OUT}=0~1000mA			1	15	mV
Temperature stability	ΔV_{OUT}				0.5		%
Long Term Stability	ΔV_{OUT}	1000 hrs, T_J=125°C			0.3		%
Operating Input Voltage	V_{IN}	I_{OUT}=100mA				15	V
Quiescent Current	I_Q	V_{IN}≤15V			5	10	mA
Current Limit	I_{LIMIT}	V_{IN}=10V, T_J=25°C	LD1117	800			mA
			LD1117A	1000			
Output Noise Voltage	e_N	B=10Hz to 10KHz, T_J=25°C			100		μV
Supply Voltage Rejection	SVR	I_{OUT}=40mA, f=120Hz, T_J=25°C, V_{IN}=8V, V_{RIPPLE}=1V_{PP}		60	75		dB
Dropout Voltage	V_D	I_{OUT}=100mA			1.00	1.10	V
		I_{OUT}=500mA			1.15	1.25	
		I_{OUT}=800mA			1.20	1.30	
		I_{OUT}=1A			1.20	1.30	
Thermal Regulation		T_A=25°C, 30ms Pulse			0.01	0.10	%/W

For LD1117/A-ADJ

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Reference Voltage	V_{REF}	V_{IN}-V_{OUT}=2V, I_{OUT}=10mA, T_J=25°C		1.225	1.25	1.275	V
Reference Voltage	V_{REF}	V_{IN}-V_{OUT}=1.4 to 10V LD1117 : I_{OUT}=10~800mA LD1117A : I_{OUT}=10~1000mA		1.225	1.25	1.275	V
Line Regulation	ΔV_{OUT}	V_{IN}-V_{OUT}=1.5 to 13.75V, I_{OUT}=10mA			0.035	0.2	%
Load Regulation	ΔV_{OUT}	V_{IN}-V_{OUT}=3V LD1117 : I_{OUT}=10~800mA LD1117A : I_{OUT}=10~1000mA			0.1	0.4	%
Temperature stability	ΔV_{OUT}				0.50		%
Long Term Stability	ΔV_{OUT}	1000 hrs, T_J=125°C			0.3		%
Operating Input Voltage	V_{IN}					15	V
Adjustment Pin Current	I_{ADJ}	V_{IN}≤15V			60	120	μA
Adjustment Pin Current Change	ΔI_{ADJ}	V_{IN}-V_{OUT}=1.4 to 10V, LD1117 : I_{OUT}=10 ~ 800mA LD1117A : I_{OUT}=10 ~ 1000mA			1	5	μA
Minimum Load Current	$I_{O(MIN)}$	V_{IN}=15V			2	5	mA
Current Limit	I_{LIMIT}	V_{IN}-V_{OUT}=5V, T_J=25°C	LD1117	800			mA
			LD1117A	1000			
Output Noise (%V_O)	e_N	B=10Hz to 10KHz, T_J=25°C			0.003		%
Supply Voltage Rejection	SVR	I_{OUT}=40mA, f=120Hz, T_J=25°C, V_{IN}-V_{OUT}=3V, V_{RIPPLE}=1V_{PP}		60	75		dB
Dropout Voltage	V_D	I_{OUT}=100mA			1.00	1.10	V
		I_{OUT}=500mA			1.15	1.25	
		I_{OUT}=800mA			1.20	1.30	
		I_{OUT}=1A			1.20	1.30	
Thermal Regulation		T_A=25°C, 30ms Pulse			0.01	0.10	%/W

■ TYPICAL APPLICATIONS

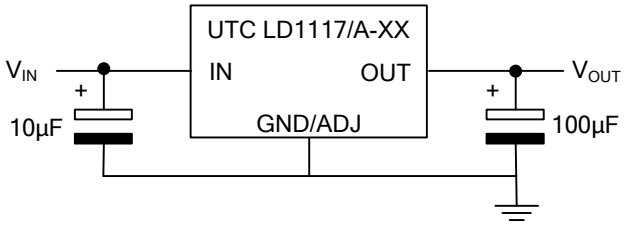


Fig.1 Tyncal Application Circuit

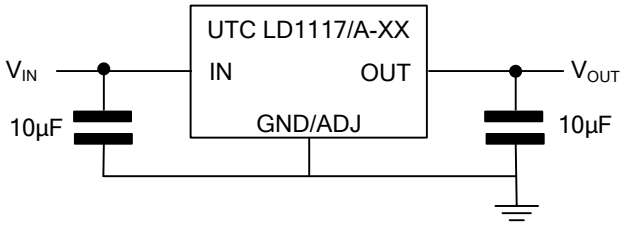


Fig.2 Tyncal Application Circuit (FOR MLCC)

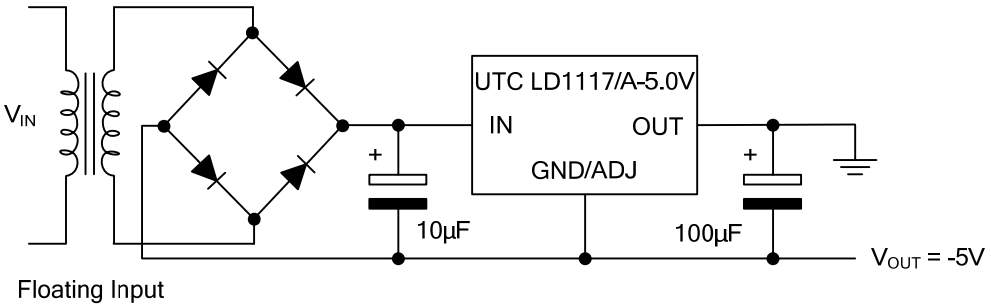


Fig.3 Negative Supply

■ TYPICAL APPLICATIONS(Cont.)

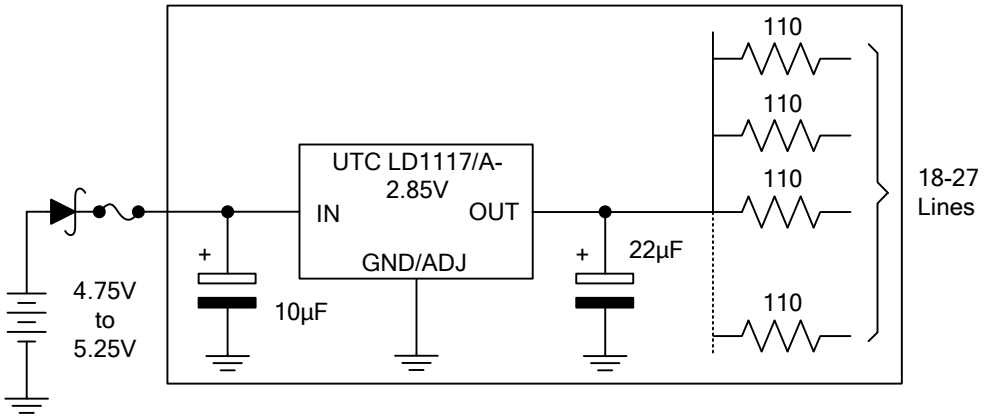


Fig.4 Active Terminator for SCSI-2 BUS

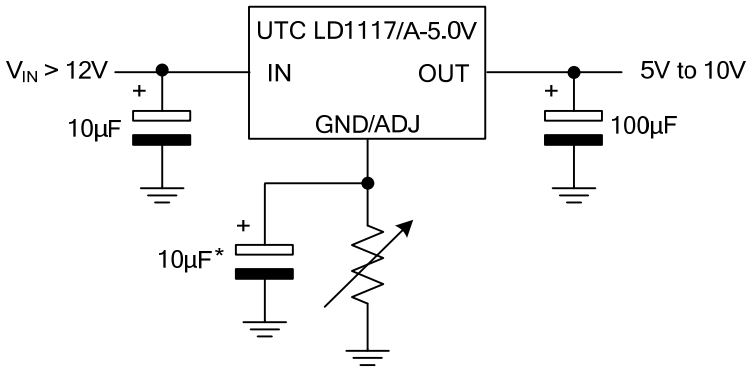


Fig.5 Circuit for Increasing Output Voltage

■ APPLICATION NOTE of LD1117/A ADJUSTABLE

The **LD1117/A** adjustable has a reference voltage of between the OUT and ADJ/GND pins. I_{ADJ} is 60μA typ. (120μA max.) and ΔI_{ADJ} is 1μA typ. (5μA max.).

R_1 is normally fixed to 120Ω.

From figure 6 we obtain:

$V_{OUT}=V_{REF}+R_2(I_{ADJ}+I_{R1})=V_{REF} + R_2(I_{ADJ}+V_{REF}/R_1)=V_{REF}(1+R_2/R_1) + R_2 \times I_{ADJ}$.

Usually R_2 value is in the range of few KΩ, so the R_2 X I_{ADJ} product could be neglected; then the above expression becomes: $V_{OUT}=V_{REF}(1+R_2/R_1)$

For better load regulation, realize a good Kelvin connection of R_1 and R_2 is important. Particularly R_1 connection must be realized very close to OUT and ADJ/GND pin, while R_2 ground connection must be placed as near as possible to the negative Load pin. Ripple rejection can be improved by introducing a 10μF electrolytic capacitor placed in parallel to the R_2 resistor (See Fig. 8)

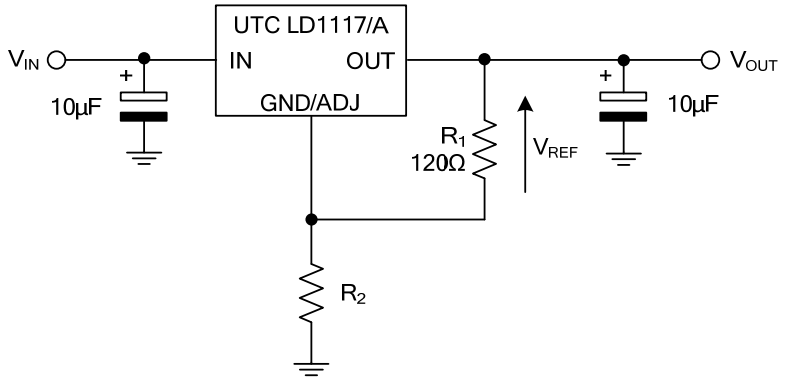


Fig.6 Adjustable Output Voltage Application Circuit

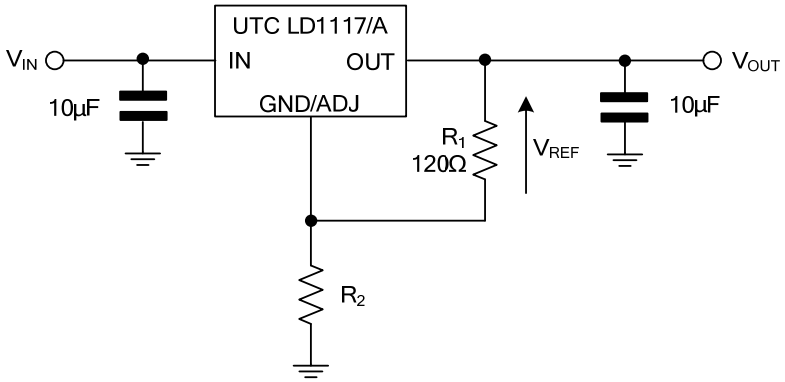


Fig.7 Adjustable Output Voltage Application Circuit (FOR MLCC)

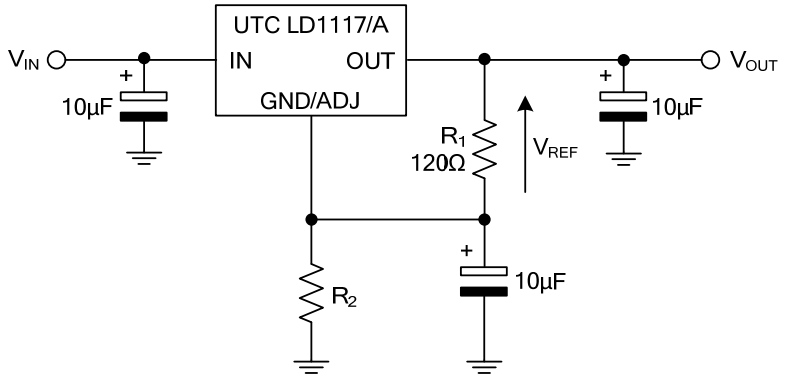
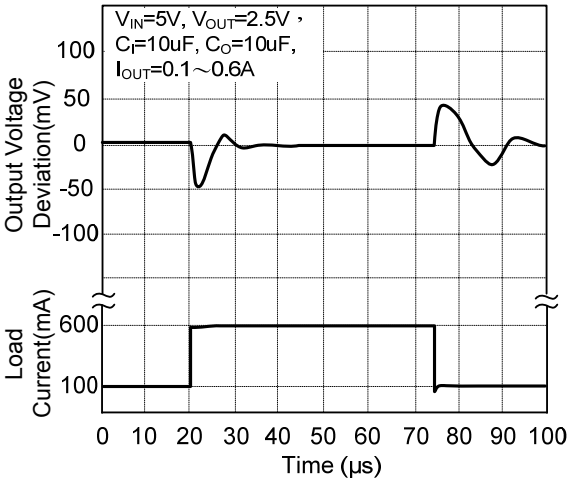


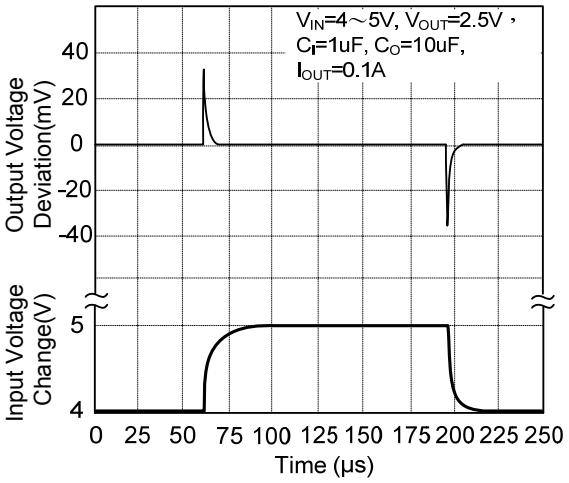
Fig.8 Adjustable Output Voltage Application with improved Ripple Rejection.

■ TYPICAL CHARACTERISTICS

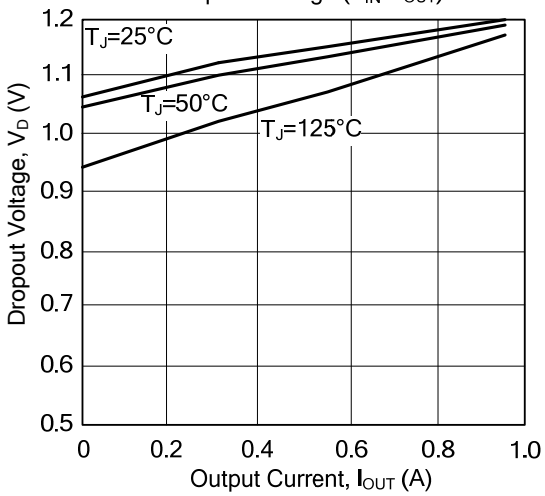
Load Transient Response



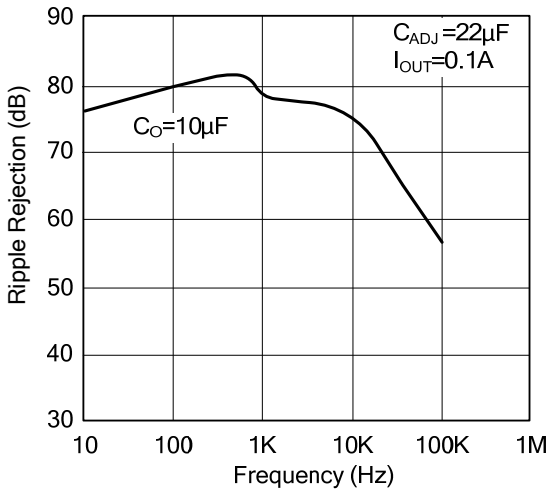
Line Transient Response



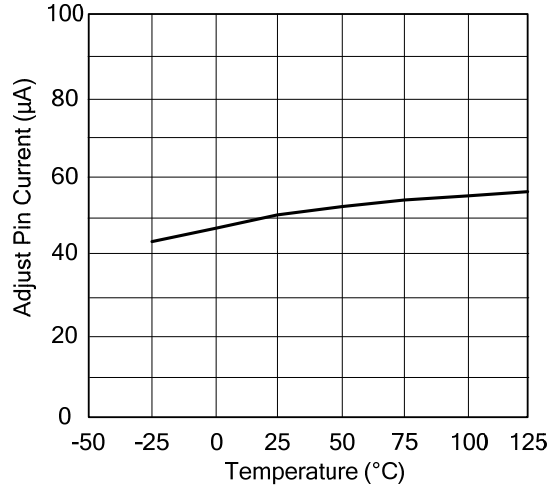
Dropout Voltage (V_{IN}-V_{OUT})



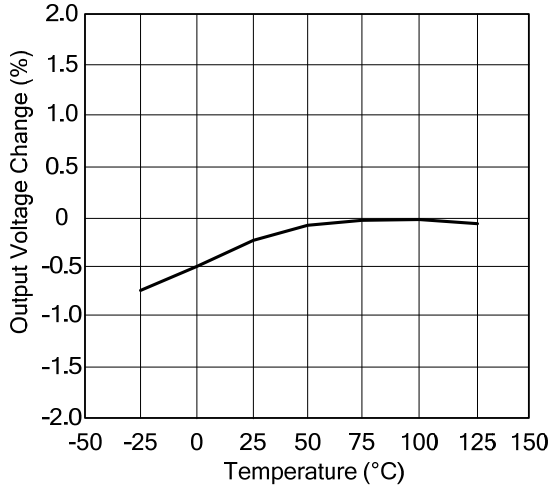
Ripple Rejection



Adjust Pin Current

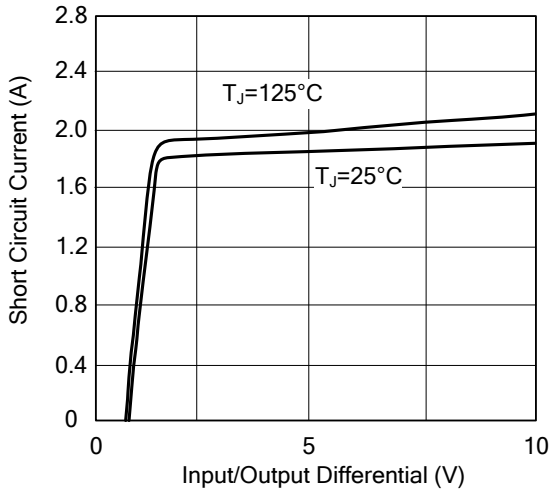


Temperature Stability

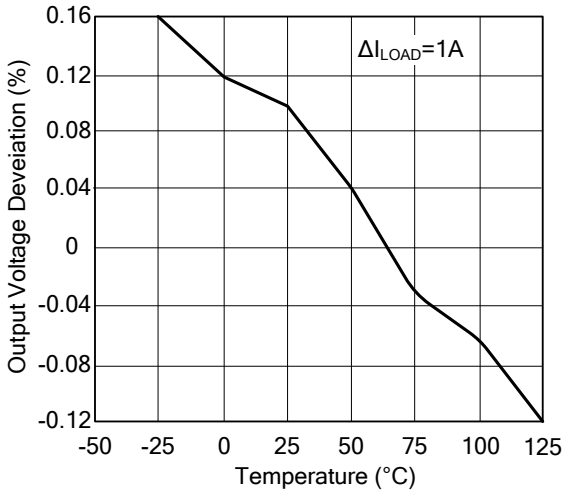


■ TYPICAL CHARACTERISTICS(Cont.)

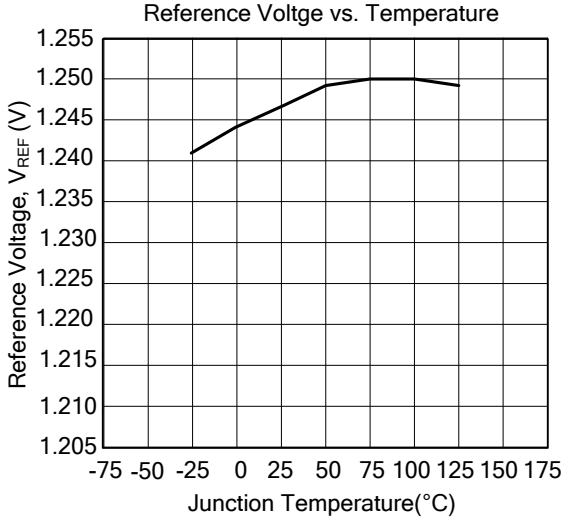
Short-Circuit Current



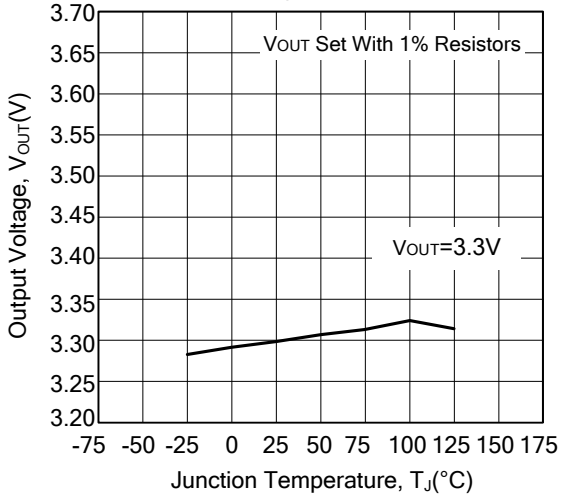
Load Regulation



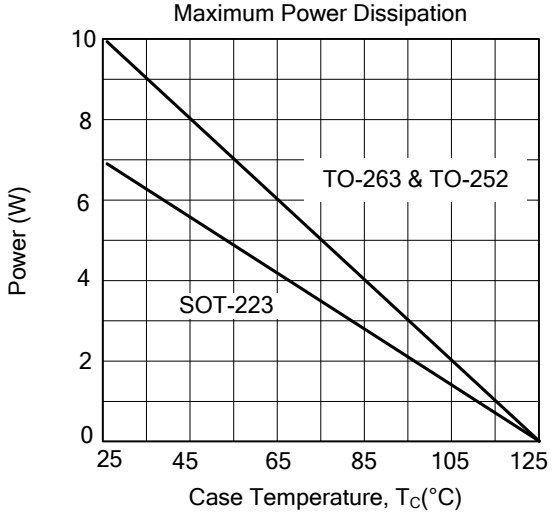
Reference Voltge vs. Temperature



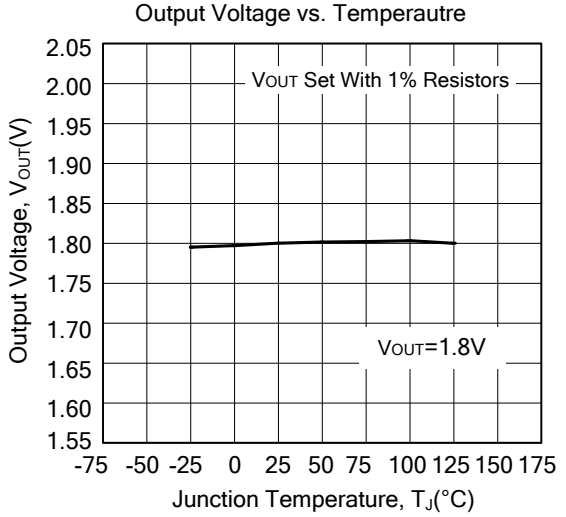
Output Voltage vs. Temperautre



Maximum Power Dissipation



Output Voltage vs. Temperautre



■ TYPICAL CHARACTERISTICS(Cont.)